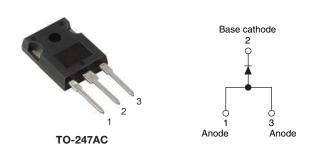


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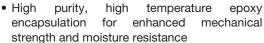
High Performance Schottky Rectifier, 65 A

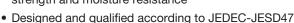


| PRODUCT SUMMARY | | | | | |
|----------------------------------|------------------|--|--|--|--|
| Package | TO-247AC | | | | |
| I _{F(AV)} | 65 A | | | | |
| V_{R} | 15 V | | | | |
| V _F at I _F | 0.46 V | | | | |
| I _{RM} max. | 870 mA at 100 °C | | | | |
| T _J max. | 125 °C | | | | |
| Diode variation | Single die | | | | |
| E _{AS} | 9 mJ | | | | |

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- Single diode configuration
- · Optimized for OR-ing applications
- Ultralow forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability





 Material categorization: For definitions of compliance please see www.vishav.com/doc?99912





HALOGEN FREE

DESCRIPTION

The VS-65PQ015... Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|-----------------------------------|----------------------------------------------|-------------|-------|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | |
| I _{F(AV)} | Rectangular waveform | 65 | А | | | |
| V _{RRM} | | 15 | V | | | |
| I _{FSM} | t _p = 5 μs sine | 1500 | А | | | |
| V _F | 65 A _{pk} , T _J = 125 °C | 0.46 | V | | | |
| T _J | Range | - 55 to 125 | °C | | | |

| VOLTAGE RATINGS | | | | | | |
|----------------------------|---------|-------------------------|---------------|---------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VS-65PQ015PbF | VS-65PQ015-N3 | UNITS | |
| Maximum DC reverse voltage | V_{R} | T _J = 100 °C | 15 | 15 | W | |
| | ۷R | T _J = 125 °C | 5 | 5 | \ \ \ | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|---------------------------------|--------------------|-------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------|-------|----|--|
| PARAMETER | SYMBOL | TEST COND | VALUES | UNITS | | |
| Maximum average forward current | I _{F(AV)} | 50 % duty cycle at T _C = 83 °C, r | 65 | | | |
| Maximum peak one cycle | I _{FSM} | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with rated | 1500 | Α | |
| non-repetitive surge current | | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 400 | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 2 A, L = 4.5 mH | | 9 | mJ | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \text{ x } V_R$ typical | | 2 | А | |



VS-65PQ015PbF, VS-65PQ015-N3

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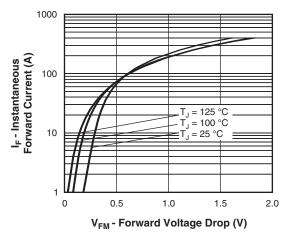
| ELECTRICAL SPECIFICATIONS | | | | | |
|--------------------------------|--------------------------------|-------------------------------------------------------------|---------------------------------------|--------|------|
| PARAMETER | SYMBOL | TEST CO | VALUES | UNITS | |
| | | 65 A | T _{.1} = 25 °C | 0.50 | V |
| Forward voltage drop | V _{FM} ⁽¹⁾ | 130 A | 11 = 23 0 | 0.71 | |
| Forward voltage drop | VFM (") | 65 A | T _ 105 °C | 0.46 | |
| | | 130 A | - T _J = 125 °C | 0.76 | |
| | I _{RM} ⁽¹⁾ | T _J = 125 °C | V _R = 5 V | 1.2 | А |
| Reverse leakage current | | T _J = 25 °C | V Datad V | 18 | - mA |
| | | T _J = 100 °C | V _R = Rated V _R | 870 | |
| Threshold voltage | V _{F(TO)} | $T_{.1} = T_{.1}$ maximum | | 0.137 | mV |
| Forward slope resistance | r _t | ıj = ıj maxımum | 4.9 | mΩ | |
| Maximum junction capacitance | C _T | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C | | 4300 | pF |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body | | 8 | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs |

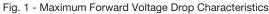
Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | |
|----------------------------------------------|-------------------|--------------------------------------|-------------|------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction temperature range | TJ | | - 55 to 125 | °C | |
| Maximum storage temperature range | T _{Stg} | | - 55 to 150 | °C | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 0.8 | | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased | 0.3 | °C/W | |
| Approximate weight | | | 6 | g | |
| Approximate weight | | | 0.21 | OZ. | |
| Mounting torque | | N | 6 (5) | kgf · cm | |
| Mounting torque maximum | | Non-lubricated threads | 12 (10) | (lbf · in) | |
| Marking device | | Case style TO-247AC (JEDEC) | 65PC | 2015 | |







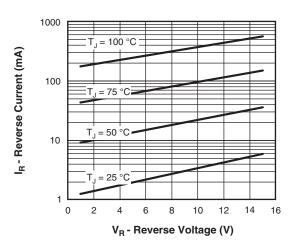


Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

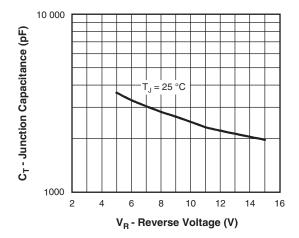


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

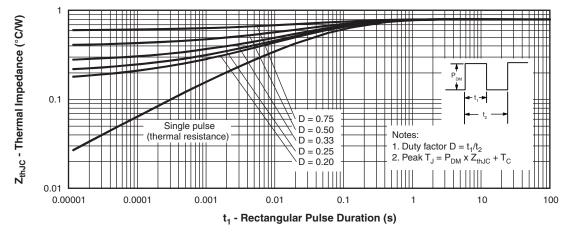


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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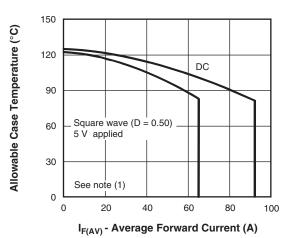


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

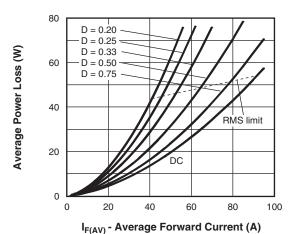


Fig. 6 - Forward Power Loss Characteristics

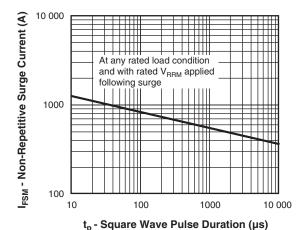


Fig. 7 - Maximum Non-Repetitive Surge Current

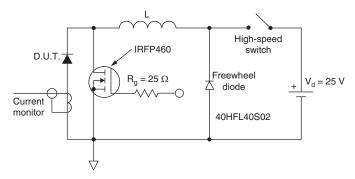


Fig. 8 - Unclamped Inductive Test Circuit

Note

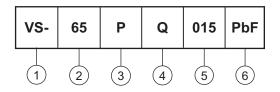
 $^{(1)}$ Formula used: $T_C = T_J$ - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 5 V

VS-65PQ015PbF, VS-65PQ015-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (65 = 65 A)
- 3 Package:

P = TO-247

- 4 Schottky "Q" series
- 5 Voltage code (015 = 15 V)
- 6 Environmental digit
 - PbF = Lead (Pb)-free and RoHS compliant
 - -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-65PQ015PbF | 25 | 500 | Antistatic plastic tube | | | |
| VS-65PQ015-N3 | 25 | 500 | Antistatic plastic tube | | | |

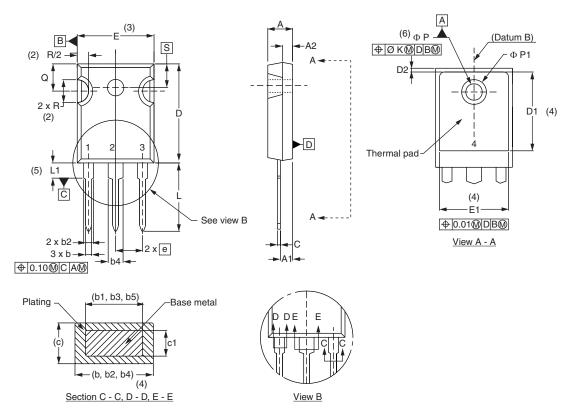
| LINKS TO RELATED DOCUMENTS | | | | | |
|--------------------------------------------|-----------------------|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95542</u> | | | | | |
| Deut eranding information | TO-247AC modified PbF | www.vishay.com/doc?95226 | | | |
| Part marking information | TO-247AC modified -N3 | www.vishay.com/doc?95007 | | | |
| SPICE model | | www.vishay.com/doc?95306 | | | |



Vishay Semiconductors

TO-247AC - 50 mils L/F

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|---------|--------|--------|-------|-------|-------|
| STWIBUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.65 | 5.31 | 0.183 | 0.209 | |
| A1 | 2.21 | 2.59 | 0.087 | 0.102 | |
| A2 | 1.17 | 1.37 | 0.046 | 0.054 | |
| b | 0.99 | 1.40 | 0.039 | 0.055 | |
| b1 | 0.99 | 1.35 | 0.039 | 0.053 | |
| b2 | 1.65 | 2.39 | 0.065 | 0.094 | |
| b3 | 1.65 | 2.34 | 0.065 | 0.092 | |
| b4 | 2.59 | 3.43 | 0.102 | 0.135 | |
| b5 | 2.59 | 3.38 | 0.102 | 0.133 | |
| С | 0.38 | 0.89 | 0.015 | 0.035 | |
| c1 | 0.38 | 0.84 | 0.015 | 0.033 | |
| D | 19.71 | 20.70 | 0.776 | 0.815 | 3 |
| D1 | 13.08 | - | 0.515 | - | 4 |

| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|---------|----------|--------|-------|-------|-------|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 0.51 | 1.35 | 0.020 | 0.053 | |
| E | 15.29 | 15.87 | 0.602 | 0.625 | 3 |
| E1 | 13.46 | - | 0.53 | - | |
| е | 5.46 | BSC | 0.215 | BSC | |
| ØK | 0.254 | | 0.0 | 10 | |
| L | 14.20 | 16.10 | 0.559 | 0.634 | |
| L1 | 3.71 | 4.29 | 0.146 | 0.169 | |
| ØΡ | 3.56 | 3.66 | 0.14 | 0.144 | |
| Ø P1 | - | 7.39 | - | 0.291 | |
| Q | 5.31 | 5.69 | 0.209 | 0.224 | |
| R | 4.52 | 5.49 | 0.178 | 0.216 | |
| S | 5.51 BSC | | 0.217 | BSC | |
| | | | | | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}$ Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



Legal Disclaimer Notice

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